





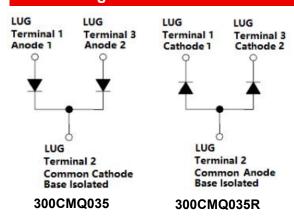
300CMQ035/300CMQ040/300CMQ045 SCHOTTKY RECTIFIER



Features

- 150℃ T_J operation
- · Center tap module
- High purity, high temperature epoxy encapsulation for
- enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Baseplate: Nickel plated; Terminals: Nickel plated
- This is a Pb Free Device
- . All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- · High current switching power supply
- Plating power supply
- Free-Wheeling diodes
- Reverse battery protection
- Converters
- UPS System
- Welding

Maximum Ratings:

Characteristics	Symbol	Condition	Max.		Units
Peak Repetitive Reverse Voltage	V_{RRM}	-	35 300CMQ035 40 300CMQ040		V
Working Peak Reverse Voltage	V_{RWM}				
DC Blocking Voltage	V_R		45	300CMQ045	
Average Rectified Forward Current	I _{F(AV)}	50% duty cycle @T _C =104°C,	150(Per Leg)		Α
Average Rectilled Forward Current		rectangular wave form	300(Per Device)		
Peak One Cycle Non-Repetitive	I _{FSM}	8.3 ms, half Sine pulse	2880		А
Surge Current (Per Leg)	IFSM	0.5 ms, mail Sine puise			
Non-Repetitive Avalanche	E _{AS}	T _J =25℃,I _{AS} =30A,L=0.67mH	150		mJ
Energy(Peg Leg)	LAS	13-20 0,143-00/1,2-0.0/11111		100	1110
Repetitive Avalanche Current		Current decaying linearly to zero	30		А
(Peg Leg)	I _{AR}	in 1 µsec Frequency limited by			
		T_J max. V_A =1.5 \times V_R typical			

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •









Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@ 150A, Pulse, T _J = 25 °C @ 300A, Pulse, T _J = 25 °C	0.55 -	0.61 0.77	V
	V _{F2}	@ 150A, Pulse, T _J = 125 °C @ 300A, Pulse, T _J = 125 °C	0.49 -	0.62 0.75	V
Reverse Current(Per Leg)*	I _{R1}	$@V_R = \text{rated } V_{R,} T_J = 25 ^{\circ}\text{C}$	0.3	15	mA
	I _{R2}	$@V_R = \text{rated } V_{R_i} T_J = 125 ^{\circ}\text{C}$	240	750	mA
Junction Capacitance(Per leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	6000	7750	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

^{*} Pulse width < 300 µs, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification		Units
Junction Temperature	Τ _J	-	-55 to +150		°C
Storage Temperature	T _{stg}	-	-55 to +150		°C
Typical Thermal Resistance Junction to Case(Per leg)	$R_{ heta JC}$	DC operation	0.50		°C/W
Typical Thermal Resistance Junction to Case(Per package)	$R_{ heta JC}$	DC operation	0.25		°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.10		°C/W
Mounting Torque	Тм	-	Mounting Torque	24(min) 35(max)	- Kg-cm
			Terminal Torque	35(min) 46(max)	
Approximate Weight	wt	-	79 g		
Case Style	PRM4 Isolated				

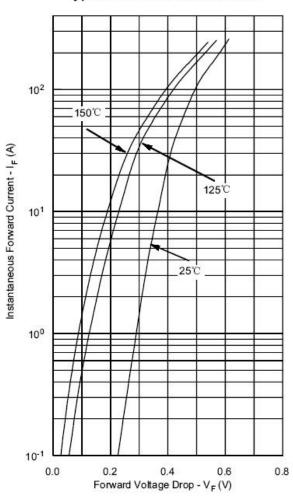




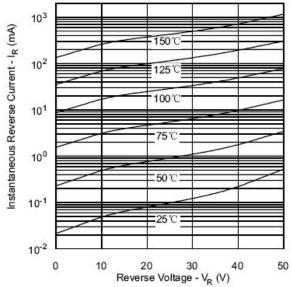


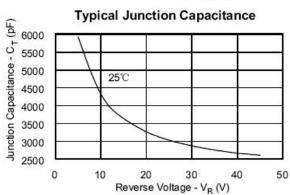
Ratings and Characteristics Curves

Typical Forward Characteristics



Typical Reverse Characteristics





[•] China - Germany - Korea - Singapore - United States •

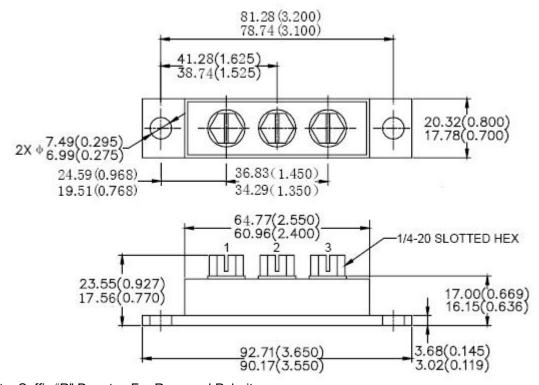






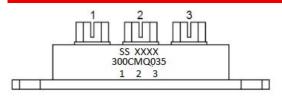


Mechanical Dimensions PRM4 Isolated(Millimeters/Inches)



Please Note: Suffix "R" Denotes For Reversed Polarity

Marking Diagram



Where XXXX is YYWW

300CMQ035 = Part name SS = SS YY = Year WW = Week

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information

Device	Package	Shipping
300CMQ SERIES	PRM4 Isolated (Pb-Free)	9 pcs/box

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.









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